TECHNICAL DATA DATA SHEET 4517, REV. -

# POWER SCHOTTKY RECTIFIER Low Reverse Leakage

## **Applications:**

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

#### Features:

- Ultra Low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	30	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle, rectangular	60	Α
Current		wave form		
Max. Peak One Cycle Non-	$I_{FSM}$	8.3 ms, half Sine wave	860	Α
Repetitive Surge Current		(per leg)		
Non-Repetitive Avalanche	$E_AS$	$T_J = 25  ^{\circ}\text{C}, I_{AS} = 1.3  \text{A},$	27	mJ
Energy		L = 40mH (per leg)		
Repetitive Avalanche	$I_{AR}$	I <sub>AS</sub> decay linearly to 0 in 1 μs	1.3	Α
Current		f limited by T <sub>J</sub> max V <sub>A</sub> =1.5V <sub>R</sub>		
Thermal Resistance	$R_{thJC}$	Per Package	0.35	°C/W
Max. Junction Temperature	Τ <sub>J</sub>	-	-65 to +150	°C
Max. Storage Temperature	$T_{stg}$	-	-65 to +150	°C

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 60A, Pulse, T <sub>J</sub> = 25 °C	0.53	V
		(per leg) measured at the leads		
	$V_{F2}$	@ 60A, Pulse, T <sub>J</sub> = 125 °C	0.43	V
		(per leg) measured at the leads		
Max. Reverse Current	I <sub>R1</sub>	$@V_R = 30V$ , Pulse,	6	mA
		$T_J = 25  ^{\circ}\text{C} \text{ (per leg)}$		
	$I_{R2}$	@V <sub>R</sub> = 30V, Pulse,	300	mA
		T <sub>J</sub> = 125 °C (per leg)		
Max. Junction Capacitance	Ст	$@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$	3300	pF
		$f_{SIG} = 1 MHz,$		
		$V_{SIG} = 50 \text{mV (p-p) (per leg)}$		

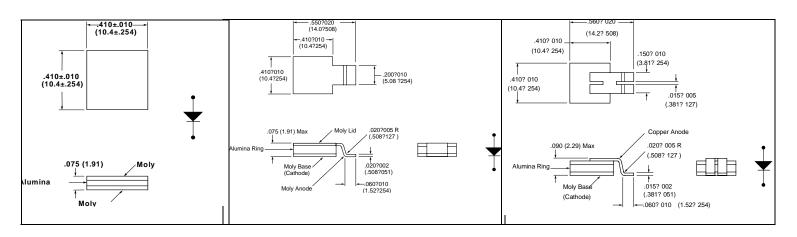
Due to the nature of the 30V Schottky devices, some degradation in  $t_{rr}$  performance at high temperatures should be expected, unlike conventional lower voltage Schottkys.

<sup>• 221</sup> West Industry Court Deer Park, NY 11729-4681 (631) 586-7600 FAX (631) 242-9798 eet 4U.com

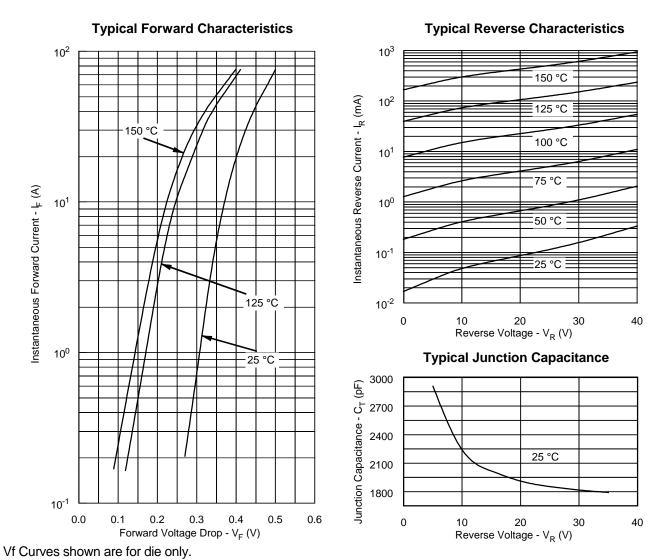
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#### Mechanical Dimensions: in inches / mm



SHD-3A SHD-3B



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#### TECHNICAL DATA

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